## NSN 5962-01-464-3420

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Maximum Power Dissipation Rating:
1.5 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15e acft; f-18 acft
Features Provided:
Monolithic and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, memory, digital, cmos ee programmable array logic, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Time Rating Per Chacteristic:
25.00 nanoseconds access
Memory Device Type:
Pal
Special Features:
Recommended operating supply voltage (vcc) 4.5 to 5.5 vdc; case outline descriptive designator mil-std-1835, gdip3-t24 or cdip4-t24
Supplementary Features:
22-input, 10-output, ee cmos, architecturally generic, programmable and-or array
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: